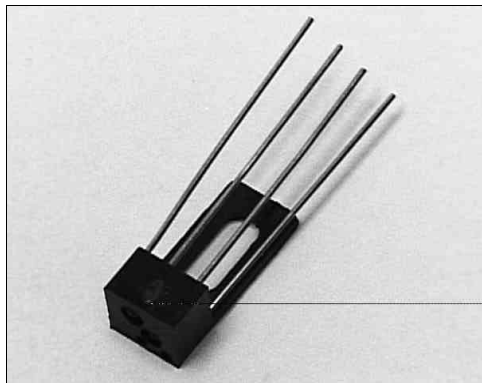


HOA2498

Reflective Sensor

FEATURES

- Choice of phototransistor or photodarlington output
- Focused for maximum response
- Wide operating temperature range (-55°C to +100°C)



INFRA-64.TIF

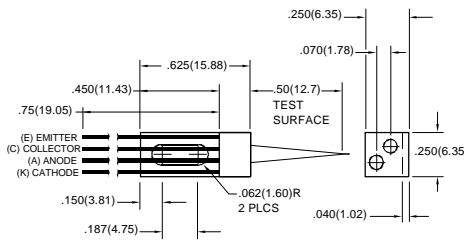
DESCRIPTION

The HOA2498 series consists of an infrared emitting diode and an NPN silicon phototransistor (HOA2498-001, -002) or photodarlington (HOA2498-003), encased side-by-side on converging optical axes in a black thermoplastic housing. The detector responds to radiation from the IRED only when a reflective object passes within its field of view. The HOA2498 series employs metal can packaged components. For additional component information see SE1450, SD1440, and SD1410.

Housing material is polyester. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

OUTLINE DIMENSIONS in inches (mm)

Tolerance 3 plc decimals ±0.010(0.25)
 2 plc decimals ±0.020(0.51)



DIM_039.ds4

HOA2498

Reflective Sensor

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	V_F			1.6	V	$I_F=20\text{ mA}$
Reverse Leakage Current	I_R			10	μA	$V_R=3\text{ V}$
DETECTOR						
Collector-Emitter Breakdown Voltage HOA2498-001, -002 HOA2498-003	$V_{(BR)CEO}$	30 15			V	$I_C=100\text{ }\mu\text{A}$
Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	5.0			V	$I_E=100\text{ }\mu\text{A}$
Collector Dark Current HOA2498-001, -002 HOA2498-003	I_{CEO}			100 250	nA	$V_{CE}=10\text{ V}$ $I_F=0$
COUPLED CHARACTERISTICS						
On-State Collector Current HOA2498-001 HOA2498-002 HOA2498-003	$I_{C(ON)}$	0.04 0.16 2.0			mA	$V_{CE}=5\text{ V}$ $I_F=30\text{ mA}$ (1)
Collector-Emitter Saturation Voltage HOA2498-001 HOA2498-002 HOA2498-003	$V_{CE(SAT)}$			0.4 0.4 1.1	V	$I_F=30\text{ mA}$ (1) $I_C=5\text{ }\mu\text{A}$ $I_C=20\text{ }\mu\text{A}$ $I_C=250\text{ }\mu\text{A}$
Rise And Fall Time HOA2498-001, -002 HOA2498-003	t_r, t_f		15 75		μs	$V_{CC}=5\text{ V}, I_C=1\text{ mA}$ $R_L=1000\text{ }\Omega$ $R_L=100\text{ }\Omega$

Notes

1. Test surface is a front surface mirror (polished aluminum, 85% reflectance) located 0.50 in.(12.7 mm) from the front surface of the device.

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -55°C to 100°C

Storage Temperature Range -55°C to 125°C

Soldering Temperature (10 sec) 260°C

IR EMITTER

Power Dissipation 75 mW (1)

Reverse Voltage 3 V

Continuous Forward Current 50 mA

DETECTOR

Collector-Emitter Voltage 30 V

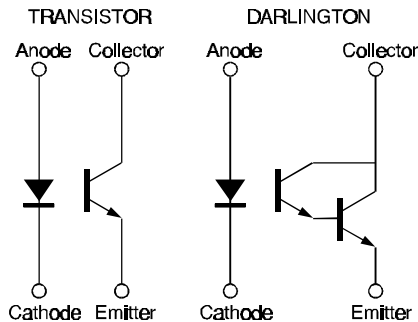
Emitter-Collector Voltage 5 V

Power Dissipation 75 mW (1)

Collector DC Current 30 mA

	TRANS.	DARLINGTON
Collector-Emitter Voltage	30 V	15 V
Emitter-Collector Voltage	5 V	5 V
Power Dissipation	75 mW (1)	75 mW (1)
Collector DC Current	30 mA	30 mA

SCHEMATIC



Notes

1. Derate linearly at 0.71 mW/°C above 25°C.

Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

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HOA2498

Reflective Sensor

Fig. 1 IRED Forward Bias Characteristics

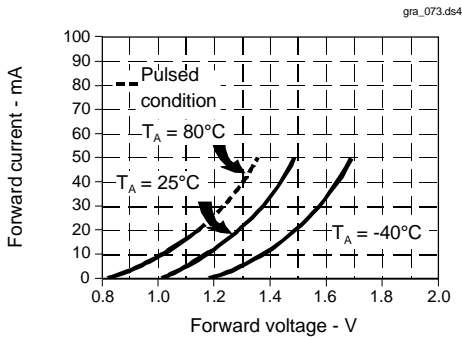


Fig. 2 Non-Saturated Switching Time vs Load Resistance

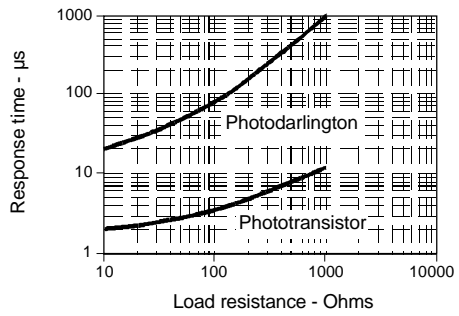


Fig. 3 Dark Current vs Temperature

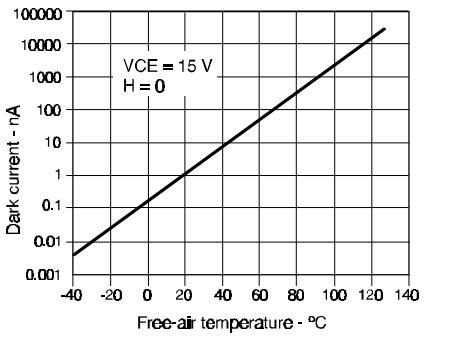


Fig. 4 Collector Current vs Ambient Temperature

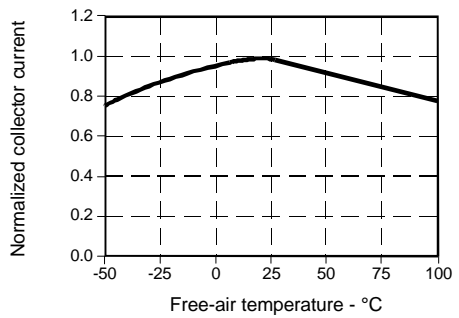


Fig. 5 Collector Current vs Distance to Reflective Surface

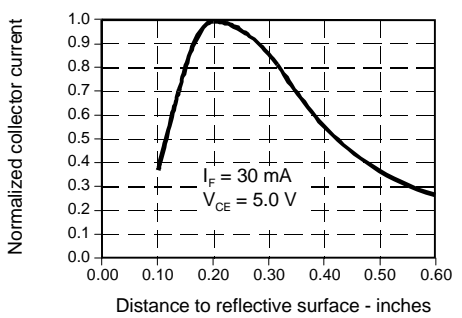
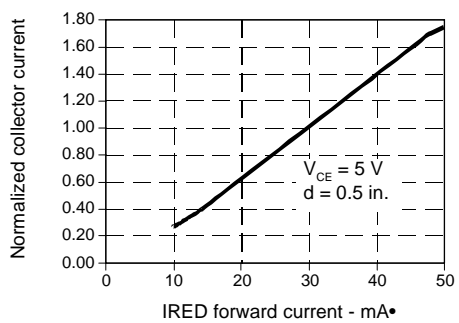


Fig. 6 Collector Current vs IRED Forward Current



All Performance Curves Show Typical Values

17 September 1997

HOA2498

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